

## Features

- Very small conduction losses
- Negligible switching losses
- Extremely fast switching
- Insulated package: TO-220FPAB
  - Insulating voltage = 2000 V DC
  - Capacitance = 12 pF
- Avalanche rated

## Description

This device is a dual center tap Schottky rectifier suited for switch mode power supply and high frequency DC to DC converters.

Packaged in TO-220AB, TO-220FPAB, I<sup>2</sup>PAK, TO-247 or D<sup>2</sup>PAK, this device is especially intended for use in low voltage, high frequency inverters, free wheeling and polarity protection applications.

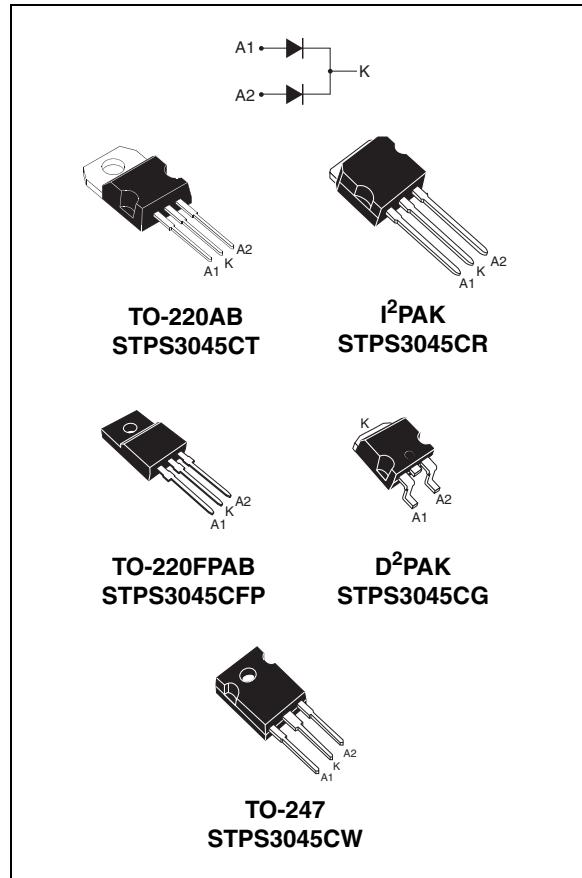


Table 1. Device summary

Symbol	Value
I <sub>F(AV)</sub>	2 x 15 A
V <sub>RRM</sub>	45 V
T <sub>j</sub> (max)	175 °C
V <sub>F</sub> (max)	0.57 V

# 1 Characteristics

**Table 2. Absolute ratings (limiting values, per diode)**

Symbol	Parameter				Value	Unit
V <sub>RRM</sub>	Repetitive peak reverse voltage				45	V
I <sub>F(RMS)</sub>	Forward rms voltage				30	A
I <sub>F(AV)</sub>	Average forward current $\delta = 0.5$		TO-220AB / D <sup>2</sup> PAK / I <sup>2</sup> PAK / TO-247	T <sub>c</sub> = 155 °C	Per diode	15
			TO-220FPAB	T <sub>c</sub> = 130 °C	Per device	30
I <sub>FSM</sub>	Surge non repetitive forward current		t <sub>p</sub> = 10 ms sinusoidal		220	A
P <sub>ARM</sub>	Repetitive peak avalanche power		t <sub>p</sub> = 1 µs, T <sub>j</sub> = 25 °C		6000	W
T <sub>stg</sub>	Storage temperature range				-65 to + 175	°C
T <sub>j</sub>	Maximum operating junction temperature <sup>(1)</sup>				+ 175	°C
dV/dt	Critical rate of rise reverse voltage				10000	V/µs

1.  $\frac{dP_{tot}}{dT_j} < \frac{1}{R_{th(j-a)}}$  condition to avoid thermal runaway for a diode on its own heatsink

**Table 3. Thermal resistance parameters**

Symbol	Parameter				Value	Unit
R <sub>th (j-c)</sub>	Junction to case	TO-220AB / D <sup>2</sup> PAK / I <sup>2</sup> PAK		Per diode	1.60	°C/W
				Total	0.95	
		TO-247		Per diode	1.5	
				Total	0.9	
		TO-220FPAB		Per diode	4	
				Total	3.2	
R <sub>th (c)</sub>	Coupling	TO-220AB / D <sup>2</sup> PAK / I <sup>2</sup> PAK / TO-247				0.30
		TO-220FPAB				2.5

When the diodes 1 and 2 are used simultaneously:

$$\Delta T_j(\text{diode 1}) = P(\text{diode1}) \times R_{th(j-c)}(\text{Per diode}) + P(\text{diode2}) \times R_{th(c)}$$

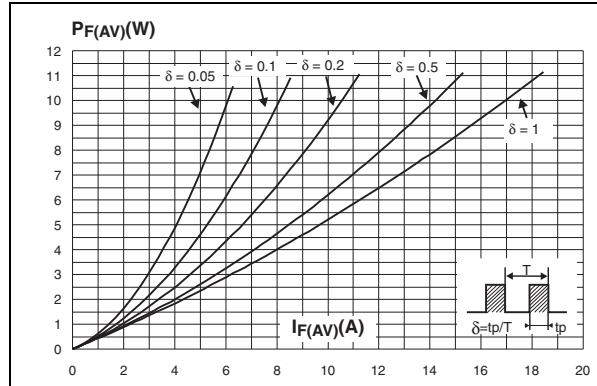
**Table 4. Static electrical characteristics (per diode)**

Symbol	Parameter	Tests conditions		Min.	Typ.	Max.	Unit
I <sub>R</sub> <sup>(1)</sup>	Reverse leakage current	T <sub>j</sub> = 25 °C	V <sub>R</sub> = V <sub>RRM</sub>			200	µA
		T <sub>j</sub> = 125 °C			11	40	mA
V <sub>F</sub> <sup>(1)</sup>	Forward voltage drop	T <sub>j</sub> = 125 °C	I <sub>F</sub> = 15 A		0.5	0.57	V
		T <sub>j</sub> = 25 °C	I <sub>F</sub> = 30 A			0.84	
		T <sub>j</sub> = 125 °C			0.65	0.72	

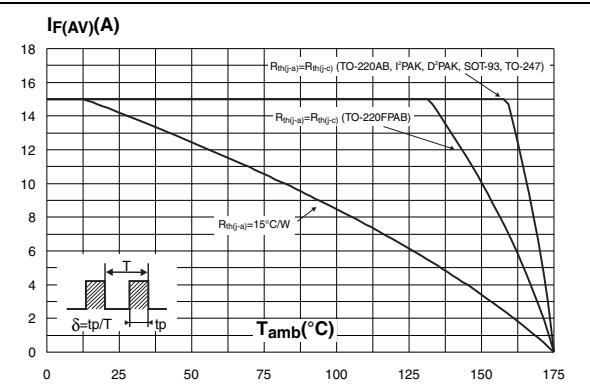
1. Pulse test: t<sub>p</sub> = 380 µs, δ < 2%

To evaluate the conduction losses use the following equation: P = 0.42 × I<sub>F(AV)</sub> + 0.01 I<sub>F(RMS)</sub><sup>2</sup>

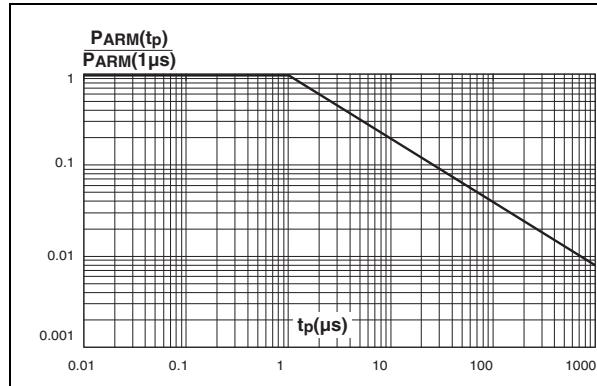
**Figure 1. Average forward power dissipation vs. average forward current (per diode)**



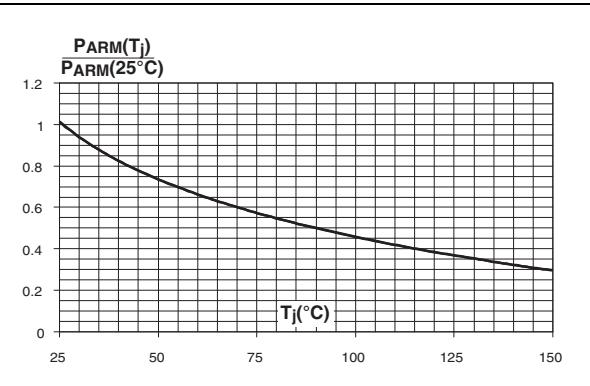
**Figure 2. Average forward current vs. ambient temperature ( $\delta = 0.5$ , per diode)**



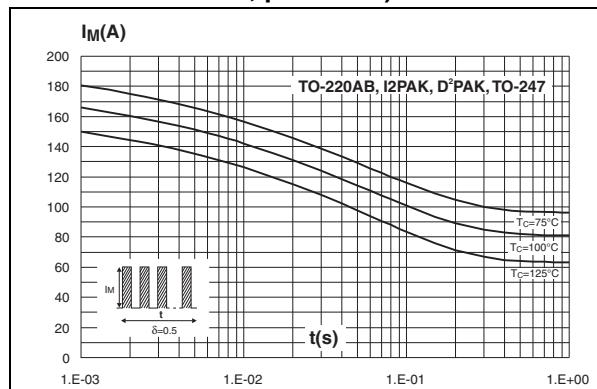
**Figure 3. Normalized avalanche power derating vs. pulse duration**



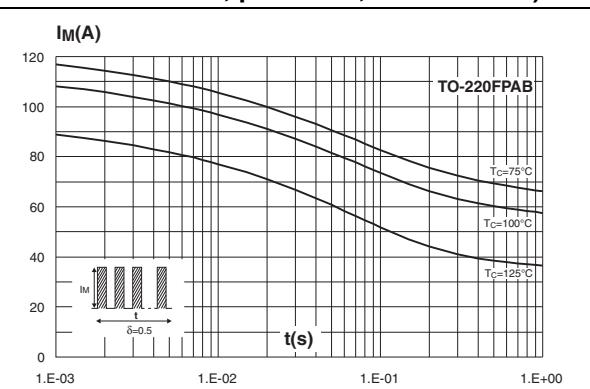
**Figure 4. Normalized avalanche power derating vs. junction temperature**



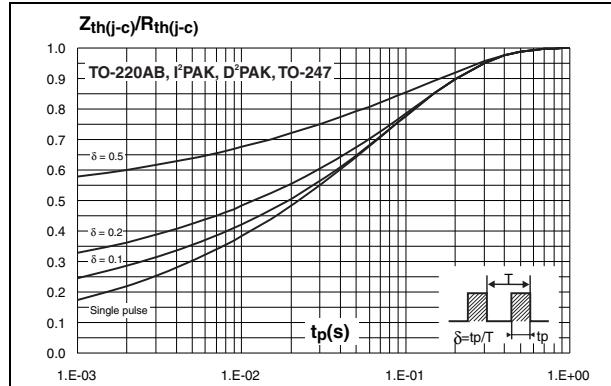
**Figure 5. Non repetitive surge peak forward current vs. overload duration (max. values, per diode)**



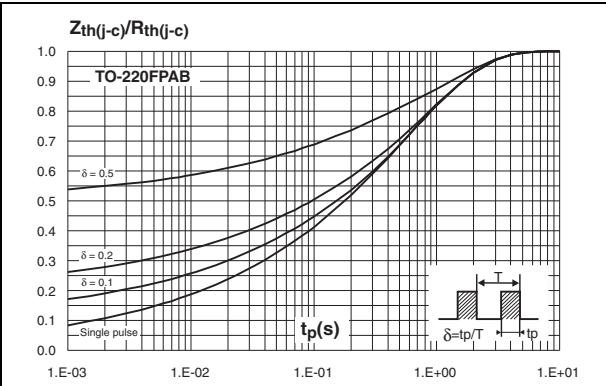
**Figure 6. Non repetitive surge peak forward current vs. overload duration (max. values, per diode, TO-220FPAB)**



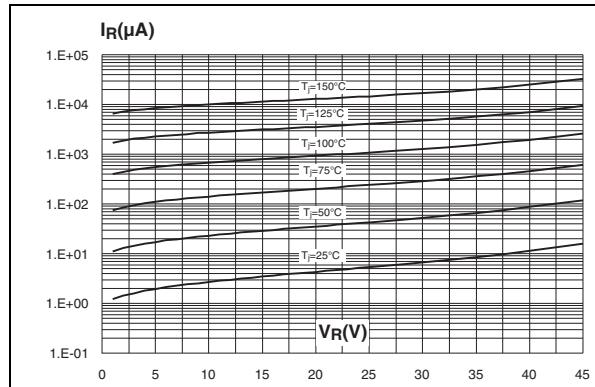
**Figure 7. Relative variation of thermal impedance junction to ambient vs. pulse duration**



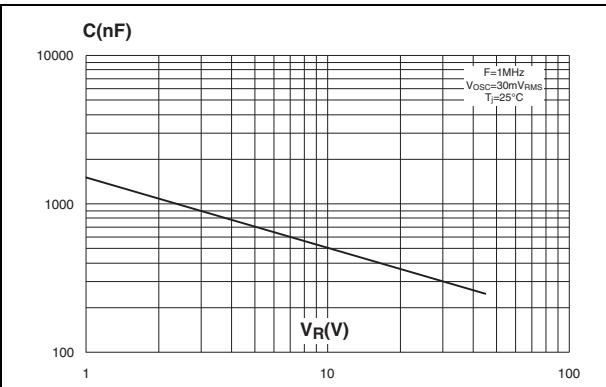
**Figure 8. Relative variation of thermal impedance junction to ambient vs. pulse duration (TO-220FPAB)**



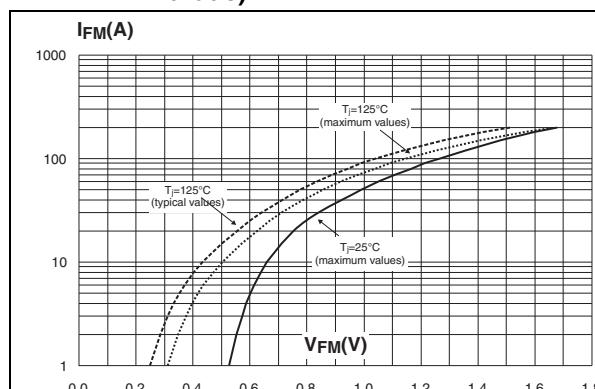
**Figure 9. Reverse leakage current vs. reverse voltage applied (typical values, per diode)**



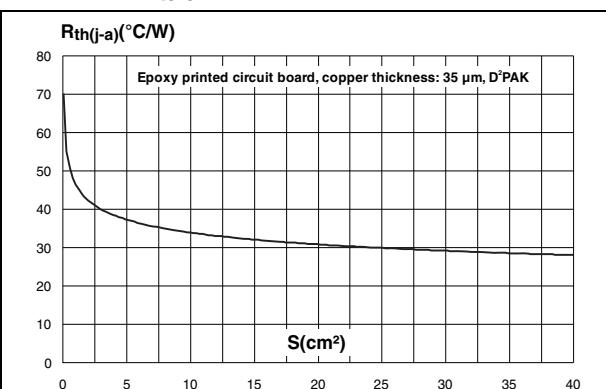
**Figure 10. Junction capacitance vs. reverse voltage applied (typical values, per diode)**



**Figure 11. Forward voltage drop vs. forward current (maximum values, per diode)**



**Figure 12. Thermal resistance junction to ambient vs. copper surface under tab**



## 2 Package information

- Epoxy meets UL94,V0
- Cooling method: by conduction (C)
- Recommended torque value: 0.4 to 0.6 N·m (TO-220AB, TO-220FPAB)
- Recommended torque value: 0.55 to 1.0 N·m (TO-247)

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: [www.st.com](http://www.st.com).  
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**Table 5. TO-220AB dimensions**

Ref.	Dimensions			
	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	4.40	4.60	0.173	0.181
C	1.23	1.32	0.048	0.051
D	2.40	2.72	0.094	0.107
E	0.49	0.70	0.019	0.027
F	0.61	0.88	0.024	0.034
F1	1.14	1.70	0.044	0.066
F2	1.14	1.70	0.044	0.066
G	4.95	5.15	0.194	0.202
G1	2.40	2.70	0.094	0.106
H2	10	10.40	0.393	0.409
L2	16.4 typ.		0.645 typ.	
L4	13	14	0.511	0.551
L5	2.65	2.95	0.104	0.116
L6	15.25	15.75	0.600	0.620
L7	6.20	6.60	0.244	0.259
L9	3.50	3.93	0.137	0.154
M	2.6 typ.		0.102 typ.	
Diam.	3.75	3.85	0.147	0.151

Devices in I<sup>2</sup>PAK with nickel-plated back frame must NOT be mounted by frame soldering like SMDs. Such devices are intended to be through-hole mounted ONLY and in no circumstances shall ST be held liable for any lack of performance or damage arising out of soldering of nickel-plated back frames.

**Table 6. I<sup>2</sup>PAK dimensions**

Ref.	Dimensions			
	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	4.40	4.60	0.173	0.181
A1	2.40	2.72	0.094	0.107
b	0.61	0.88	0.024	0.035
b1	1.14	1.70	0.044	0.067
c	0.49	0.70	0.019	0.028
c2	1.23	1.32	0.048	0.052
D	8.95	9.35	0.352	0.368
e	2.40	2.70	0.094	0.106
e1	4.95	5.15	0.195	0.203
E	10	10.40	0.394	0.409
L	13	14	0.512	0.551
L1	3.50	3.93	0.138	0.155
L2	1.27	1.40	0.050	0.055

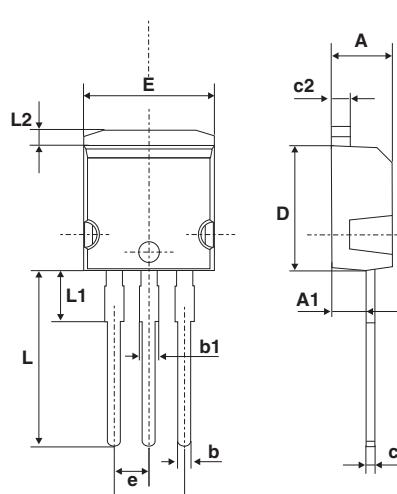
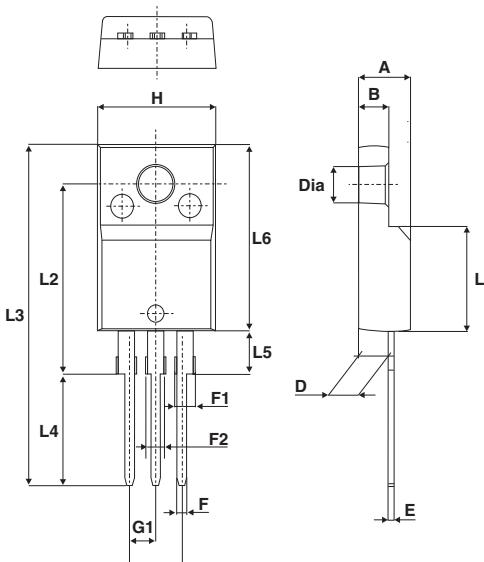


Table 7. TO-220FPAB dimensions

Ref.	Dimensions			
	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	4.4	4.6	0.173	0.181
B	2.5	2.7	0.098	0.106
D	2.5	2.75	0.098	0.108
E	0.45	0.70	0.018	0.027
F	0.75	1	0.030	0.039
F1	1.15	1.70	0.045	0.067
F2	1.15	1.70	0.045	0.067
G	4.95	5.20	0.195	0.205
G1	2.4	2.7	0.094	0.106
H	10	10.4	0.393	0.409
L2	16 Typ.		0.63 Typ.	
L3	28.6	30.6	1.126	1.205
L4	9.8	10.6	0.386	0.417
L5	2.9	3.6	0.114	0.142
L6	15.9	16.4	0.626	0.646
L7	9.00	9.30	0.354	0.366
Dia.	3.00	3.20	0.118	0.126



The technical drawing illustrates the physical dimensions of the TO-220FPAB package. It features a top view showing the lead spacing and a side view showing the height and lead thickness. Key dimensions include:  
- Top View: Lead spacing L1 = 10 mm, Lead thickness L2 = 16 mm, Lead height L3 = 28.6 mm, Lead width L4 = 9.8 mm, Lead thickness L5 = 2.9 mm, Lead height L6 = 15.9 mm, Lead width L7 = 9.00 mm.  
- Side View: Total height H = 10 mm, Lead thickness A = 4.4 mm, Lead thickness B = 2.5 mm, Lead thickness C = 0.45 mm, Lead thickness D = 0.75 mm, Lead thickness E = 0.118 mm, Lead thickness F = 0.354 mm, Lead thickness G = 0.114 mm, Lead thickness H = 0.386 mm, Lead thickness F1 = 1.15 mm, Lead thickness F2 = 1.15 mm, Lead thickness G1 = 2.4 mm, Lead thickness Dia. = 3.00 mm.

**Table 8.** D<sup>2</sup>PAK dimensions

Ref.	Dimensions			
	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	4.40	4.60	0.173	0.181
A1	2.49	2.69	0.098	0.106
A2	0.03	0.23	0.001	0.009
B	0.70	0.93	0.027	0.037
B2	1.14	1.70	0.045	0.067
C	0.45	0.60	0.017	0.024
C2	1.23	1.36	0.048	0.054
D	8.95	9.35	0.352	0.368
E	10.00	10.40	0.393	0.409
G	4.88	5.28	0.192	0.208
L	15.00	15.85	0.590	0.624
L2	1.27	1.40	0.050	0.055
L3	1.40	1.75	0.055	0.069
M	2.40	3.20	0.094	0.126
R	0.40 typ.		0.016 typ.	
V2	0°	8°	0°	8°

\* FLAT ZONE NO LESS THAN 2mm

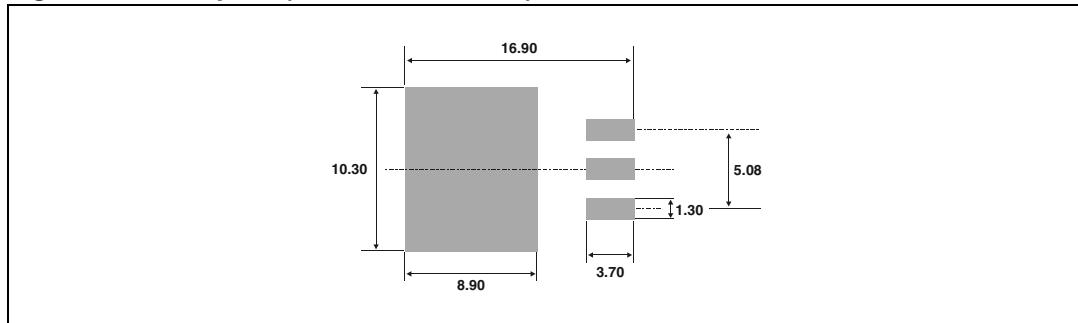
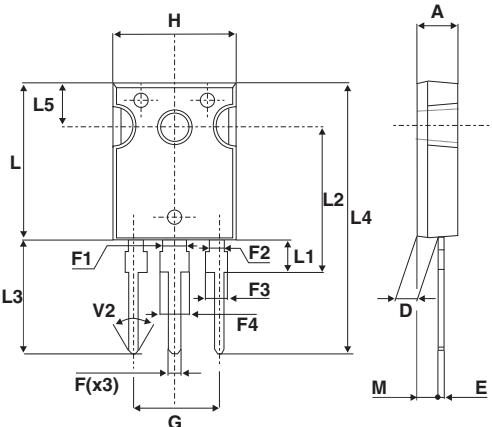
**Figure 13.** Footprint (dimensions in mm)

Table 9. TO-247 dimensions

Ref.	Dimensions			
	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	4.85	5.16	0.191	0.203
D	2.20	2.60	0.086	0.102
E	0.40	0.80	0.015	0.031
F	1.00	1.40	0.039	0.055
F1	3.00 typ.		0.118 typ.	
F2	2.00 typ.		0.079 typ.	
F3	1.90	2.40	0.075	0.094
F4	3.00	3.40	0.118	0.134
G	10.90 typ.		0.429 typ.	
H	15.45	16.03	0.608	0.631
L	19.85	21.09	0.781	0.830
L1	3.70	4.30	0.146	0.169
L2	18.30	19.13	0.720	0.753
L3	14.20	20.30	0.559	0.799
L4	34.05	41.38	1.341	1.629
L5	5.35	6.30	0.211	0.248
M	2.00	3.00	0.079	0.118
V	5° typ.		5° typ.	
V2	60° typ.		60° typ.	
Dia.	3.55	3.65	0.140	0.144



### 3 Ordering information

**Table 10. Ordering information**

Order code	Marking	Package	Weight	Base qty	Delivery mode
STPS3045CT	STPS3045CT	TO-220AB	2.23 g	50	Tube
STPS3045CR	STPS3045CR	I <sup>2</sup> PAK	1.49 g	50	Tube
STPS3045CFP	STPS3045CFP	TO-220FPAB	2.0 g	50	Tube
STPS3045CG	STPS3045CG	D <sup>2</sup> PAK	1.48 g	50	Tube
STPS3045CG-TR	STPS3045CG			1000	Tape and reel
STPS3045CW	STPS3045CW	TO-247	4.46 g	30	Tube

### 4 Revision history

**Table 11. Document revision history**

Date	Revision	Changes
July-2003	6E	Last update.
06-Nov-2012	7	Removed SOT-93 and TOP-3I packages. <a href="#">Table 2</a> : Operating range ( $T_j$ ) extension from -40 to +175° C, $I_{F(AV)}$ per diode updated to 15 A. Updated “Total” values in <a href="#">Table 3</a> . Updated tables in <a href="#">Section 2: Package information</a> .

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